THYRISTOR MODULE

AK90GB40/80







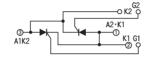
Power ThyristorModule AK90GB series are designed for various rectifier circuits and power controls. For your circuit application. following internal connections and wide voltage ratings up to 800V are available, and electrically isolated mounting base make your mechanical design easy.

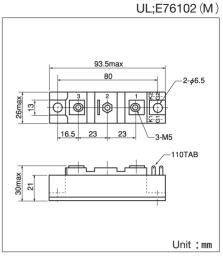
Isolated mounting base

- IT (AV) 90A, IT (RMS) 200A, ITSM 1800A
- di/dt 200 A/ μs
 dv/dt 500V/ μs

(Applications) AC/DC motor drives Heater controls Light dimmers Static switches

Internal Configurations





■Maximum Ratings

(Tj=25°C unless otherwise specified)

Symbol	Itom	Ratings		Unit
	Item	AK90GB40	AK90GB80	Offic
VDRM	Repetitive Peak Off-State Voltage	400	800	V

Symbol		Item	Conditions	Ratings	Unit
IT (AV)	Average On	-State Current	Single phase, half wave, 180° conduction, Tc: 91℃	90	Α
IT (RMS)	R.M.S. On-S	State Current	Tc:91℃	200	Α
Ітѕм	Surge On-State Current ½cycle, 50Hz/60Hz, peak value, non-reqetitive		1650/1800	Α	
l²t	I²t		Value for one cycle of surge current	15000	A ² S
Рам	Peak Gate Power Dissipation			10	W
Pg (AV)	Average Gate Power Dissipation			3	W
lгдм	Peak Gate Current			3	А
VFGM	Peak Gate Voltage (Forward)			10	V
VRGM	Peak Gate Voltage (Reverse)			5	V
di/dt	Critical Rate of Rise of On-State Current		Ig=100mA, Tj=25°C, VD= $\frac{1}{2}$ VDRM, dIg/dt=0.1A/ μ s	200	A/μs
Viso	Isolation Breakdown Voltage (R.M.S.)		A.C. 1 minute	2500	V
Tj	Operating Junction Temperature			− 40∼ + 125	℃
Tstg	Storage Temperature			− 40∼ + 125	°C
	Mounting Torque	Mounting (M6)	Recommended Value 2.5~3.9 (25~40)	4.7 (48)	N·m
		Terminal (M5)	Recommended Value 1.5~2.5 (15~25)	2.7 (28)	(kgf·cm)
	Mass		Typical Value	170	g

■Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit	
IDRM	Repetitive Peak Off-State Current, max.	at VDRM, Single phase, half wave, Tj=125℃	30	mA	
Vтм	Peak On-State Voltage, max.	On-State Current 270A, Tj=125°C Inst. measurement	1.30	V	
Igt/Vgt	Gate Trigger Current/Voltage, max.	Tj=25℃, Iτ=1A, VD=6V	100/3	mA/V	
Vgd	Non-Trigger Gate, Voltage. min.	Tj=125°C, VD=1/2√DRM	0.25	V	
tgt	Turn On Time, max.	Iτ=90A, Ig=100mA, Tj=25°C, Vb=1/2Vbrм, dIg/dt=0.1A/μs	10	μS	
dv/dt	Critical Rate of Rise of Off-State Voltage, min.	Tj=125°C, VD=2/₃VDRM, Exponential wave.	500	V/μs	
lн	Holding Current, typ.	Tj=25℃	50	mA	
ΙL	Lutching Current, typ.	Tj=25℃	100	mA	
Rth (j-c)	Thermal Impedance, max.	Junction to case, per ½ Module	0.30	°0 /\\	
		Junction to case, per 1 Module	0.15	°C/W	

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